POSTERS - SESSION #2

TOPIC: Defect engineering, nano-science and technology

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| 3 | Alena | Nikolskaia | 89 | Modification of Ga₂O₃ by ion implantation |
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| 5 | Ana S. | Sousa | 111 | Radio-Frequency Magnetron Sputtering and Annealing of Ga₂O₃ Thin Films |
| 6 | Bárbara | Konrad | 32 | Coarsening of Embedded Ag nanoparticles under Ne ⁺ ion irradiation |
| 7 | Daniela | Pereira | 109 | Incorporation of modified MoO₃ crystals and pseudo-layers into Field Effect Transistors |
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| 17 | Martin | Chicoine | 136 | Formation of Crystalline Si _{1-x} Ge _x Top Layers By Ion Implantation In Crystalline Si |
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| 20 | Pierre | Couture | 110 | IBIC: ion beam induced charge, nanobeam mapping photodiode and response of a diamond-based microdosimeter devices assessing charge |
| 21 | Robert | Elliman | 3 | Controlling the Thermal Properties of Graphene by Defect Engineering |
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| 25 | Yadong | Wei | 198 | Multiple phases and electronic structures of silicon monoxide |
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Topic: Ion Beam processing of materials

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| 27 | Abdalla | Zaki | 9 | Effects of helium on the structural evolution and migration behavior of silver and strontium implanted into polycrystalline SiC |
| 28 | Abdirash | Akilbekov | 71 | Radiation resistance of aluminum-magnesium spinel: optical effects of high-energy ion irradiation |
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Topic: Ion Beam processing of materials

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| 31 | Claudia | Montanari | 85 | Machine learning modeling of the stopping power experimental data |
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| 35 | Erik | Rohkamm | 74 | Characterization of a RF-excited broad ion beam source relevant for the machining of surfaces used for optical applications |
| 36 | Filip | Ferencik | 58 | Ion Beam Synthesis of High Oxidation State Palladium and Copper Oxides |
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| 47 | Martin | Becker | 84 | Capabilities of ion-beam processing with radio-frequency ion sources |
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| 50 | Ulrich | Wahl | 115 | Fluence and doping dependence of lattice location of ion implanted Mg in GaN |
| 51 | Xuhui | Yao | 29 | Effective Li dendrite penetration reduction in solid-state batteries through Xe ion created surface compressive stress |
| 52 | Jiranat | Techarang | 44 | Low-energy Heavy-ion Beam Capable of Simultaneous Induction of Multiple Chromosomal Aberrations for Rice Mutation |
| 53 | Jiranat | Techarang | 45 | Low-energy Ion Beam Induced Brown-planthopper Resistant Thai Jasmine Rice Mutants |

TOPIC: New accelerator systems and single ion implantation

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| 53 | João | Cruz | 223 | Nitrogen targets production and characterization for 14N(p,g) ¹⁵ O reaction measurement at LUNA-MV |
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